General Purpose Peak EMI Reduction IC

Functional Description

P3P8220A/AH is a versatile, 1.8V/2.5V/3.3V Peak EMI reduction IC. P3P8220A accepts an input clock from an external reference and delivers a 1x modulated clock output.

P3P8220A is a Low drive part and P3P8220AH is a High drive part. Refer to *DC/AC Electrical characteristic* table.

P3P8220A/AH operates with 1.8V/2.5V/3.3V supply and is available in an 8 Pin, WDFN (2 mm x 2 mm) Package.

General Features

- 1x, LVCMOS Peak EMI Reduction
- Supports Non-continuous Input Clock Applications
- Input / Output Frequency Range: Up to 60 MHz
- Low and High Drive Part
- Supply Voltage: 1.8 V±0.1 V

2.5 V±0.2 V

3.3 V±0.3 V

- 8-Pin, WDFN(2 mm x 2 mm) Package
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Application

• P3P8220A is Targeted Towards Consumer Electronic Applications

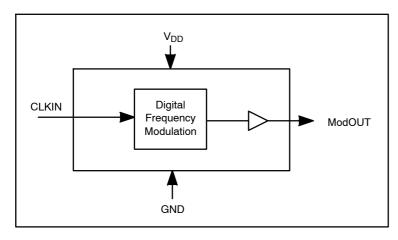


Figure 1. Block Diagram



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MARKING DIAGRAM



WDFN8 CASE 511AQ

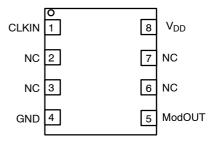


GH = Specific Device Code

M = Date Code

= Pb-Free Device

PIN CONFIGURATION



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

Table 1. PIN DESCRIPTION

Pin#	Pin Name	Туре	Description			
1	CLKIN	I	External reference Clock Input			
2	NC		connection			
3	NC		No connection			
4	GND	Р	Ground			
5	ModOUT	0	uffered Modulated Clock output.			
6	NC		No connection			
7	NC		No connection			
8	V_{DD}	Р	1.8V/2.5V/3.3V Supply Voltage			

Table 2. OPERATING CONDITIONS

Symbol	Description	Min	Max	Unit
V _{DD}	Supply Voltage 1.8 V 2.5 V 3.3 V	1.7 2.3 3.0	1.9 2.7 3.6	V
T _A	Operating Temperature (Ambient Temperature)	0	70	°C
C _L	Load Capacitance		15	pF
C _{IN}	Input Capacitance		7	pF

Table 3. ABSOLUTE MAXIMUM RATING

Symbol	Description	Rating	Unit
$V_{DD,}V_{IN}$	Voltage on any input pin with respect to Ground	-0.5 to +4.6	V
T _{STG}	Storage temperature	-65 to +125	°C
T _s	Max. Soldering Temperature (10 sec)	260	°C
T _J	Junction Temperature	150	°C
T_DV	Static Discharge Voltage (As per JEDEC STD22- A114-B)	2	KV

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

NOTE: These are stress ratings only and are not implied for functional use. Exposure to absolute maximum ratings for prolonged periods of time may affect device reliability.

Table 4. ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Conditions		Min	Тур	Max	Unit
V _{DD(1.8V)}	Supply Voltage			1.7	1.8	1.9	V
V _{DD(2.5V)}				2.3	2.5	2.7	
V _{DD(3.3V)}				3	3.3	3.6	
V _{IL}	Input LOW Voltage					0.35*V _{DD}	V
V _{IH}	Input HIGH Voltage			0.65*V _{DD}		V _{DD} +0.3	V
V _{OL}	Output LOW Voltage	P3P8220A	$V_{DD(1.8V)}$, $I_{OL} = 4mA$			0.25*V _{DD}	٧
			V _{DD(2.5V, 3.3V)} , I _{OL} = 8mA				
		P3P8220AH	$V_{DD(1.8V)}$, $I_{OL} = 6mA$				
			$V_{DD(2.5V, 3.3V)}$, $I_{OL} = 12mA$				
V _{OH}	Output HIGH Voltage	P3P8220A	$V_{DD(1.8V)}$, $I_{OL} = -4mA$	0.75*V _{DD}			٧
			$V_{DD(2.5V, 3.3V)}$, $I_{OL} = -8mA$				
		P3P8220AH	V _{DD(1.8V)} , I _{OL} =- 6mA				
			V _{DD(2.5V, 3.3V)} , I _{OL} = -12mA				
I _{CC}	Static Supply Current	CLKIN pulled LOW	V _{DD(1.8V)}			1.3	mA
			V _{DD(2.5V)}			1.5	
			V _{DD(3.3V)}			1.7	
I _{DD}	Dynamic Supply Current	V _{DD(1.8V)}	15 MHz			2.3	mA
			60 MHz			6.0	
		V _{DD(2.5V)}	15 MHz			3.2	
			60 MHz			8.0	
		V _{DD(3.3V)}	15 MHz			4.5	
			60 MHz			12	
C _L	Load Capacitance					15	pF
Z ₀	Output Impedance	V _{DD(1.8V)}	P3P8220A		50		Ω
			P3P8220AH		30		
		V _{DD(2.5V)}	P3P8220A		36]
			P3P8220AH		24]
		V _{DD(3.3V)}	P3P8220A		30		1
			P3P8220AH		20		1

Table 5. SWITCHING CHARACTERISTICS

Parameter Test Conditions				Min	Тур	Max	Unit
Input Frequency						60	MHz
ModOUT						60	
Output Rise Time (Notes 1 & 2)	Measured between 20% to 80%	V _{DD(1.8V)}	P3P8220A		3.0	5.0	ns
			P3P8220AH		2.0	4.0	
		V _{DD(2.5V)}	P3P8220A		1.8	3.0	
			P3P8220AH		1.2	2.5	
		V _{DD(3.3V)}	P3P8220A		1.4	2.5	
			P3P8220AH		1.0	1.6	
Output Fall Time (Notes 1 & 2)	Measured between 20% to 80%	V _{DD(1.8V)}	P3P8220A		2.4	4.0	
			P3P8220AH		1.6	3.0	-
		V _{DD(2.5V)}	P3P8220A		1.8	3.0	
			P3P8220AH		1.2	2.0	
		V _{DD(3.3V)}	P3P8220A		1.4	2.0	
			P3P8220AH		1.0	1.6	
Output Duty Cycle (Notes 1, 2 & 3)	Measured at VDD/2	<u> </u>	I	45	50	55	%
Cycle-to-Cycle Jitter (Note 1)	Unloaded spreaded output	V _{DD(1.8V)}	15 MHz		±350		ps
			60 MHz		±200		1
		V _{DD(2.5V)}	15 MHz		±500		1
			60 MHz		±150		
		V _{DD(3.3V)} 1	15 MHz		±750		1
			60 MHz		±200		1
Maximum Input-Output Delay	Unloaded spreaded output	V _{DD(1.8V)}	1			7.5	ns
(Notes 1 & 2)		V _{DD(2.5V)}				7.5	1
		V _{DD(3.3V)}				7.5	1

Parameter is guaranteed by design and characterization. Not 100% tested in production.
All parameters are specified with 15 pF loaded outputs.
For an input Duty Cycle (typ) of 50%.

SWITCHING WAVEFORMS

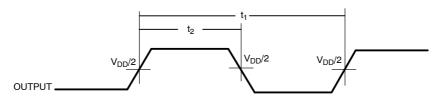


Figure 2. Duty Cycle Timing

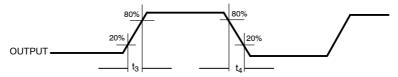


Figure 3. Output Rise/Fall Time

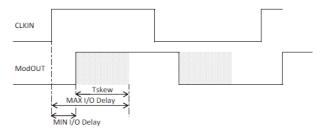
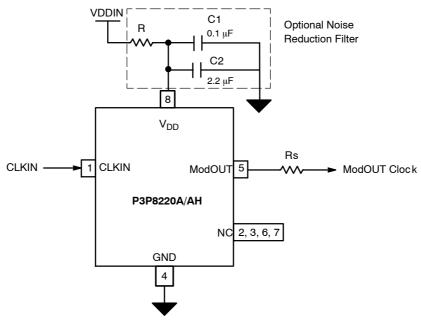


Figure 4. Input - Output Propagation Delay



NOTE: Refer Pin Description table for Functionality details.

Figure 5. Typical Application Circuit

NOTE: Device to Device variation of T_{skew} and I/O delay is $\pm\,20\%.$

ORDERING INFORMATION

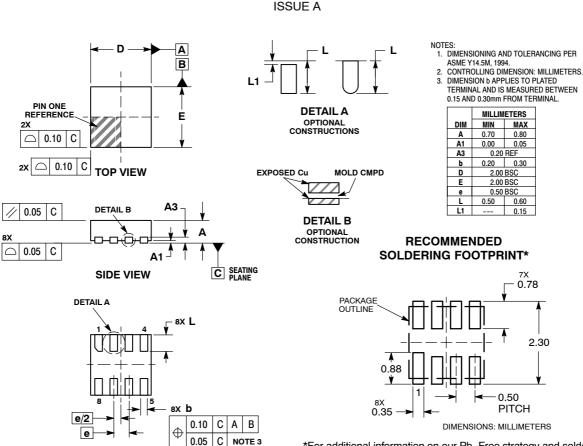
Ordering Code	Marking	Temperature	Package Type	Shipping [†]
P3P8220AG-08CR	GH	0°C to +70°C	8-pin (2 mm x 2 mm) WDFN (Pb-Free)	Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}A "microdot" placed at the end of last row of marking or just below the last row toward the center of package indicates Pb-Free.

PACKAGE DIMENSIONS

WDFN8 2x2, 0.5P CASE 511AQ-01 ISSUE A



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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